NSN 5961-00-321-1642

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-321-1642 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.120 inches **Overall Height:** 0.200 inches **Overall Width:** 0.325 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage, dc all transistor and 15.0 collector to emitter voltage, dc all transistor and 4.5 breakdown voltage, emitter-to-base, collector open all transistor **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 3.5 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No